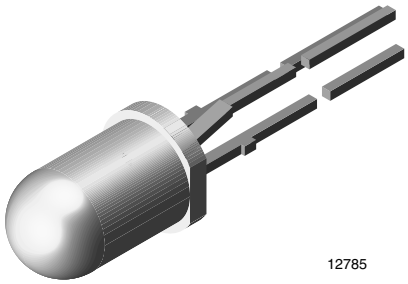
Silicon NPN Phototransistor



FEATURES

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- High photo sensitivity
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: φ = ± 15°
- Base terminal connected
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

Pb-free

e4

RoHS COMPLIANT

HALOGEN FREE

GREEN (5-2008)

DESCRIPTION

BPV11 is a silicon NPN phototransistor with high radiant sensitivity in clear, T-1¾ plastic package with base terminal. It is sensitive to visible and near infrared radiation.

APPLICATIONS

- Detector for industrial electronic circuitry, measurement and control

PRODUCT SUMMARY			
COMPONENT	I_{ca} (mA)	φ (deg)	$\lambda_{0.1}$ (nm)
BPV11	10	± 15	450 to 1080

Note

- Test condition see table “Basic Characteristics”

ORDERING INFORMATION			
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
BPV11	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Collector base voltage		V_{CBO}	80	V
Collector emitter voltage		V_{CEO}	70	V
Emitter base voltage		V_{EBO}	5	V
Collector current		I_C	50	mA
Collector peak current	t_p/T = 0.5, $t_p \leq$ 10 ms	I_{CM}	100	mA
Power dissipation	$T_{amb} \leq$ 47 °C	P_V	150	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Soldering temperature	t ≤ 5 s, 2 mm from body	T_{sd}	260	°C
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm²	R_{thJA}	350	K/W

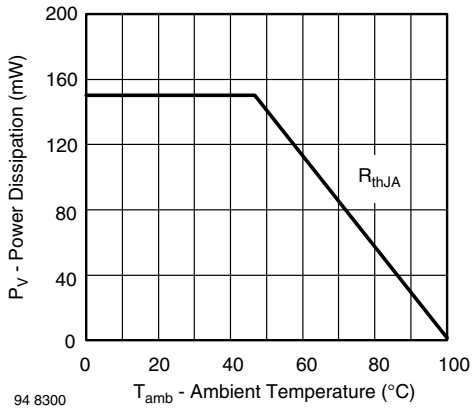


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Collector emitter breakdown voltage	I_C = 1 mA	$V_{(BR)CEO}$	70			V
Collector emitter dark current	V_{CE} = 10 V, E = 0	I_{CEO}		1	50	nA
DC current gain	V_{CE} = 5 V, I_C = 5 mA, E = 0	h_{FE}		450		
Collector emitter capacitance	V_{CE} = 0 V, f = 1 MHz, E = 0	C_{CEO}		15		pF
Collector base capacitance	V_{BE} = 0 V, f = 1 MHz, E = 0	C_{CBO}		19		pF
Collector light current	E_e = 1 mW/cm², λ = 950 nm, V_{CE} = 5 V	I_{ca}	3	10		mA
Angle of half sensitivity		φ		± 15		deg
Wavelength of peak sensitivity		λ_p		850		nm
Range of spectral bandwidth		$\lambda_{0.1}$		450 to 1080		nm
Collector emitter saturation voltage	E_e = 1 mW/cm², λ = 950 nm, I_C = 1 mA	V_{CEsat}		130	300	mV
Turn-on time	V_S = 5 V, I_C = 5 mA, R_L = 100 Ω	t_{on}		6		µs
Turn-off time	V_S = 5 V, I_C = 5 mA, R_L = 100 Ω	t_{off}		5		µs
Cut-off frequency	V_S = 5 V, I_C = 5 mA, R_L = 100 Ω	f_c		110		kHz

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

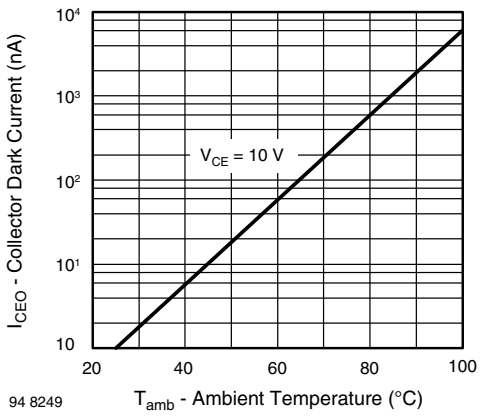


Fig. 2 - Collector Dark Current vs. Ambient Temperature

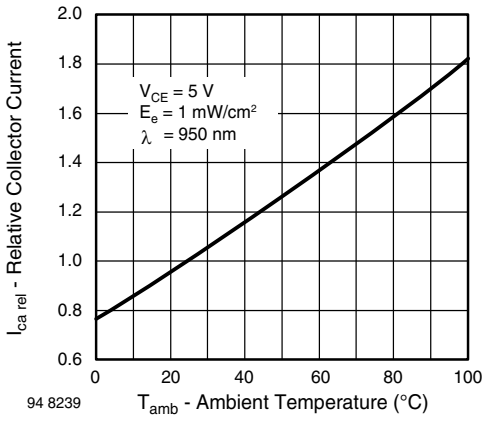


Fig. 3 - Relative Collector Current vs. Ambient Temperature

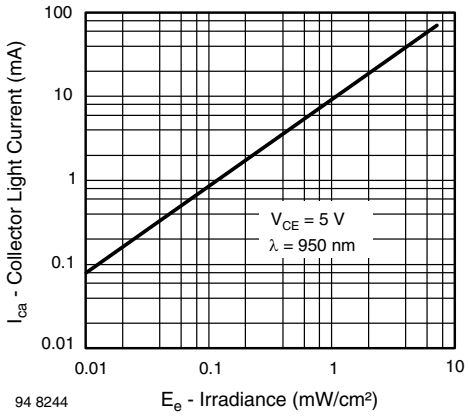


Fig. 4 - Collector Light Current vs. Irradiance

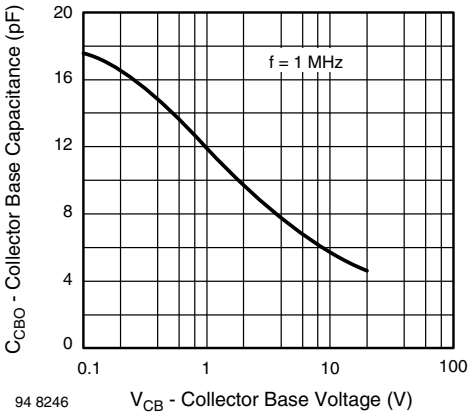


Fig. 7 - Collector Base Capacitance vs. Collector Base Voltage

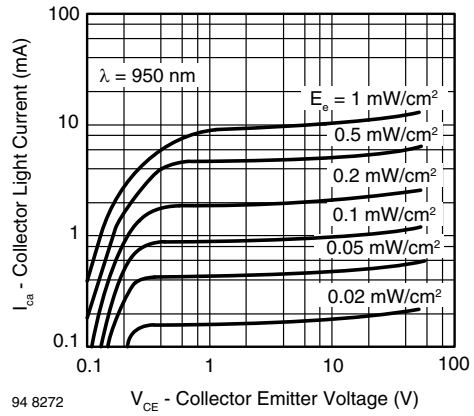


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

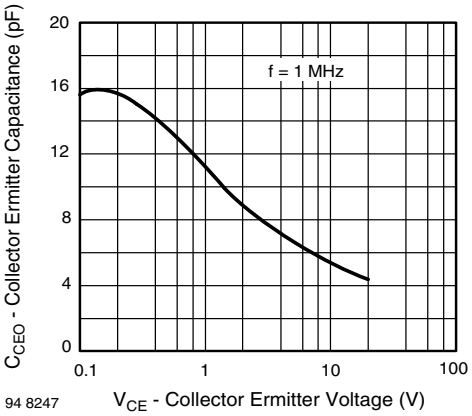


Fig. 8 - Collector Emitter Capacitance vs. Collector Emitter Voltage

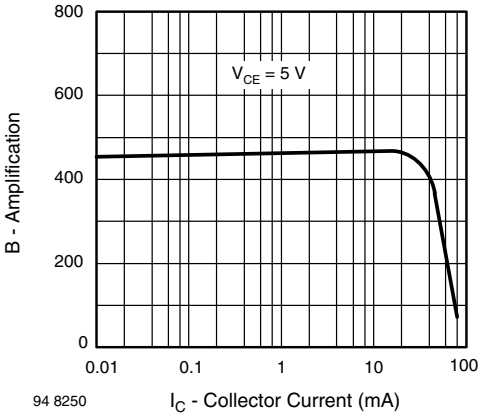


Fig. 6 - Amplification vs. Collector Current

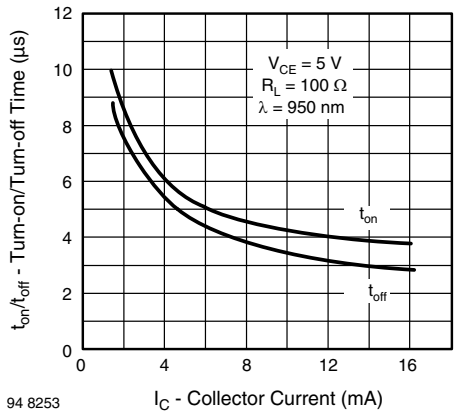


Fig. 9 - Turn-on/Turn-off Time vs. Collector Current

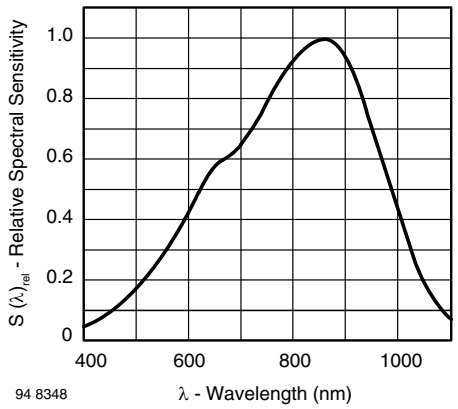


Fig. 10 - Relative Spectral Sensitivity vs. Wavelength

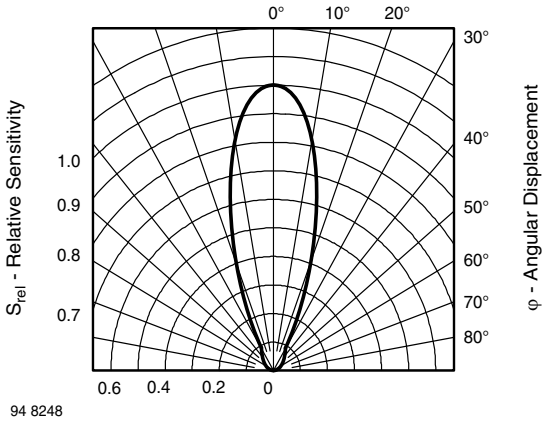
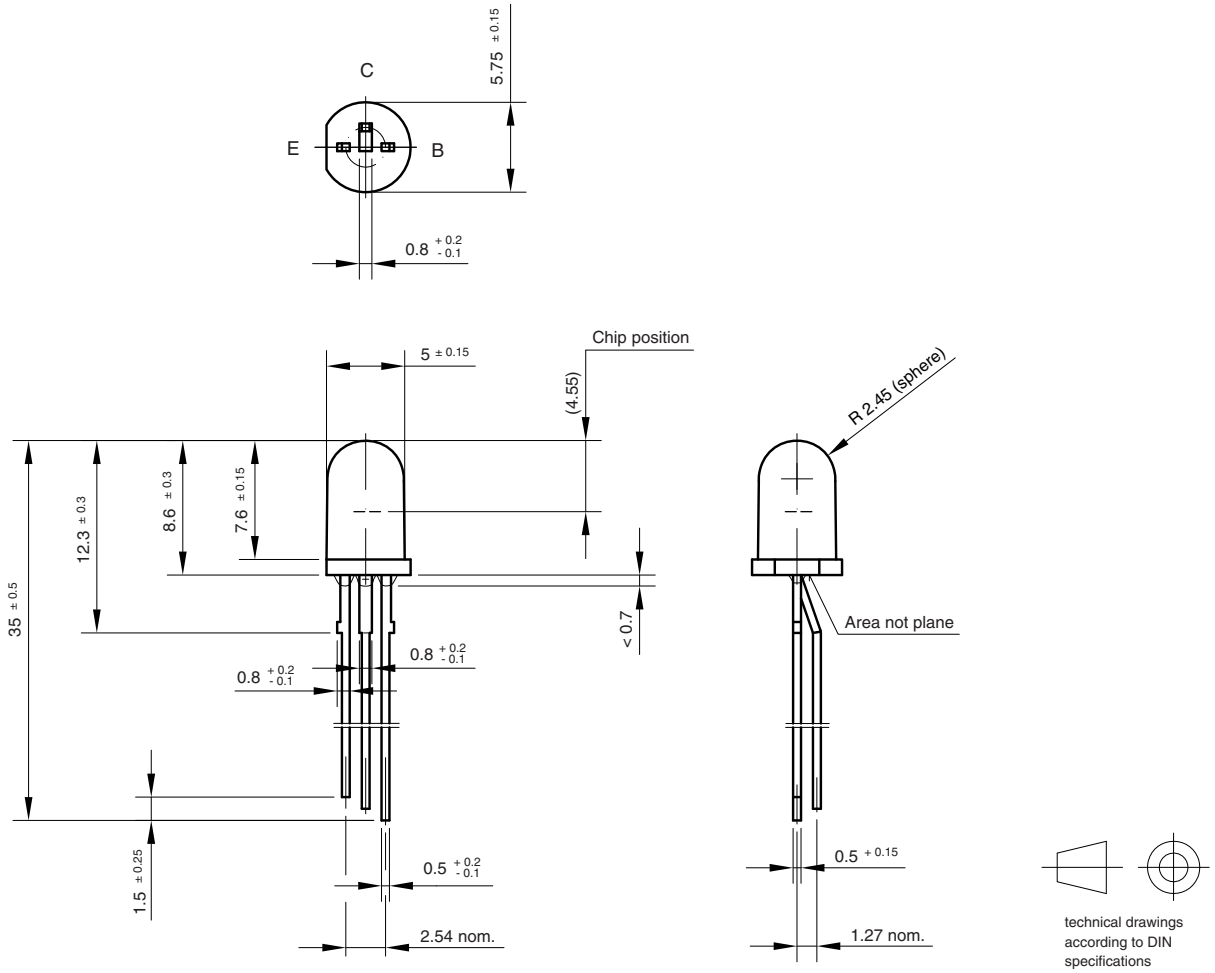


Fig. 11 - Relative Radiant Sensitivity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters



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- Подбор аналогов;
- Консультации по применению компонента;
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- Техническая поддержка проекта;
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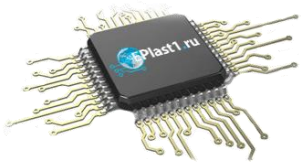

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